

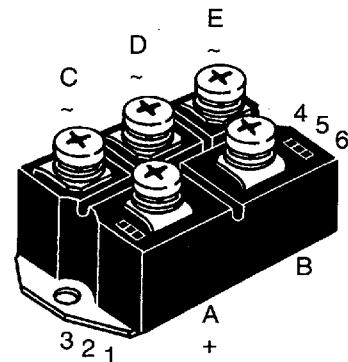
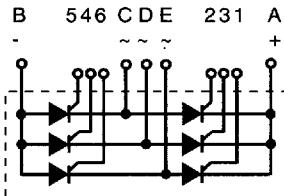
# Three-Phase Full Controlled Rectifier Bridges, B6C

VTO 110

VTO 175

 $V_{RRM} = 1200 - 1600 \text{ V}$  $I_{dAVM} = 110/167 \text{ A}$ 

$V_{RSM}$	$V_{RRM}$	Type
$V_{DSM}$	$V_{DRM}$	
V	V	
1300	1200	VTO 110-12io7
1500	1400	VTO 110-14io7
1700	1600	VTO 110-16io7
		VTO 175-12io7
		VTO 175-14io7
		VTO 175-16io7



Symbol	Test Conditions	Maximum Ratings		
		VTO 110	VTO 175	
$I_{dAV}$	$T_c = 85^\circ\text{C}$ ; module per leg	110	167	A
$I_{FRMS}, I_{TRMS}$		58	89	A
$I_{FSM}, I_{TSM}$	$T_{vj} = 45^\circ\text{C}$ ; $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	1150	1500	A
	$T_{vj} = T_{vjm}$ $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	1230	1600	A
$\int i^2 dt$	$T_{vj} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	1000	1350	A
		1070	1450	A
$(di/dt)_{cr}$	$T_{vj} = T_{vjm}$ repetitive, $I_T = 50 \text{ A}$ $f = 400 \text{ Hz}$ , $t_p = 200 \mu\text{s}$ $V_D = 2/3 V_{DRM}$ $I_G = 0.3 \text{ A}$ , non repetitive $di_G/dt = 0.3 \text{ A}/\mu\text{s}$ , $I_T = 1/3 \cdot I_{dAV}$	6600	11200	$\text{A}^2\text{s}$
		6280	10750	$\text{A}^2\text{s}$
	$T_{vj} = T_{vjm}$ $t = 10 \text{ ms}$ (50 Hz), sine $V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	5000	9100	$\text{A}^2\text{s}$
		4750	8830	$\text{A}^2\text{s}$
$(dv/dt)_{cr}$	$T_{vj} = T_{vjm}$ ; $V_{DR} = 2/3 V_{DRM}$ $R_{GK} = \infty$ ; method 1 (linear voltage rise)	1000		$\text{V}/\mu\text{s}$
$V_{RGM}$		10		V
$P_{GM}$	$T_{vj} = T_{vjm}$ $t_p = 30 \mu\text{s}$ $I_T = I_{TAVM}$ $t_p = 500 \mu\text{s}$ $t_p = 10 \text{ ms}$	$\leq 10$ $\leq 5$ $\leq 1$ 0.5		W
$P_{GAVM}$				W
$T_{vj}$		-40...+125		$^\circ\text{C}$
$T_{vjm}$		125		$^\circ\text{C}$
$T_{stg}$		-40...+125		$^\circ\text{C}$
$V_{ISOL}$	50/60 Hz, RMS $t = 1 \text{ min}$ $I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	2500 3000		$\text{V}_\sim$
$M_d$	Mounting torque (M6) Terminal connection torque (M6)	5-15 5-15 300		Nm lb.in. g
Weight	typ.			

Data according to DIN/IEC 747 and refer to a single thyristor/diode unless otherwise stated.  
IXYS reserves the right to change limits, test conditions and dimensions.

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Symbol	Test Conditions	Characteristic Values			
		VTO 110	VTO 175		
$I_R, I_D$	$V_R = V_{RRM}; V_D = V_{DRM}$ $T_{VJ} = T_{VJM}$ $T_{VJ} = 25^\circ C$	$\leq$ $\leq$	5 0.3	mA mA	
$V_F, V_T$	$I_F, I_T = 200 A, T_{VJ} = 25^\circ C$	$\leq$	1.75 1.57	V	
$V_{TO}$	For power-loss calculations only	0.85	0.85	V	
$r_T$	$(T_{VJ} = 125^\circ C)$	6	3.5	$m\Omega$	
$V_{GT}$	$V_D = 6 V; T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$	$\leq$ $\leq$	1.5 1.6	V	
$I_{GT}$	$V_D = 6 V; T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$	$\leq$ $\leq$	100 200	mA	
$V_{GD}$	$T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$	$\leq$	0.2	V	
$I_{GD}$	$T_{VJ} = T_{VJM}; V_D = 2/3 V_{DRM}$	$\leq$	5	mA	
$I_L$	$I_G = 0.3 A; t_G = 30 \mu s$ $dI_G/dt = 0.3 A/\mu s$	$T_{VJ} = 25^\circ C$	$\leq$	450	mA
$I_H$	$T_{VJ} = 25^\circ C; V_D = 6 V; R_{GK} = \infty$	$\leq$	200	mA	
$t_{gd}$	$T_{VJ} = 25^\circ C; V_D = 1/2 V_{DRM}$ $I_G = 0.3 A; dI_G/dt = 0.3 A/\mu s$	$\leq$	2	$\mu s$	
$R_{thJC}$	per thyristor (diode); DC current	0.65	0.46	K/W	
	per module	0.108	0.077	K/W	
$R_{thJK}$	per thyristor (diode); DC current	0.8	0.55	K/W	
	per module	0.133	0.092	K/W	
$d_s$	Creeping distance on surface	10	mm		
$d_A$	Creepage distance in air	9.4	mm		
$a$	Max. allowable acceleration	50	$m/s^2$		

Dimensions in mm (1 mm = 0.0394")

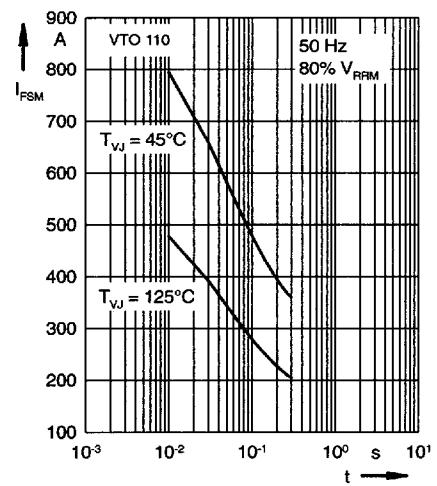
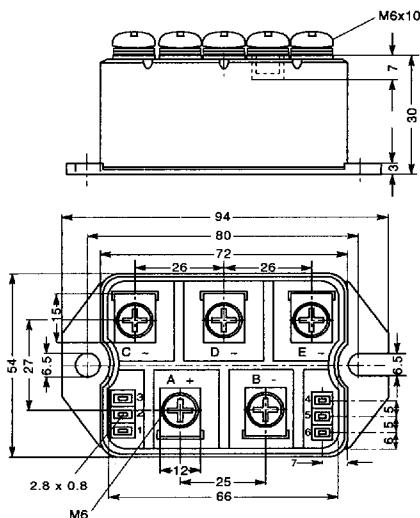
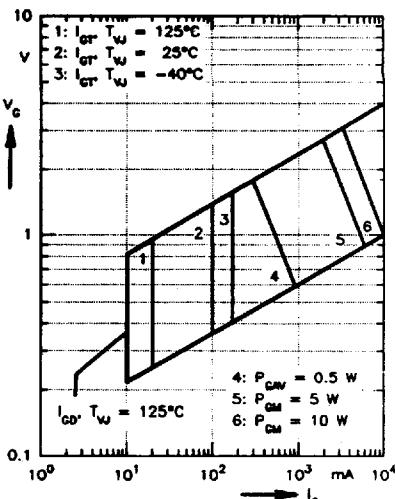
Fig. 3 Surge overload current  
 $I_{FSM}$ : Crest value,  $t$ : duration

Fig. 1 Gate trigger characteristics

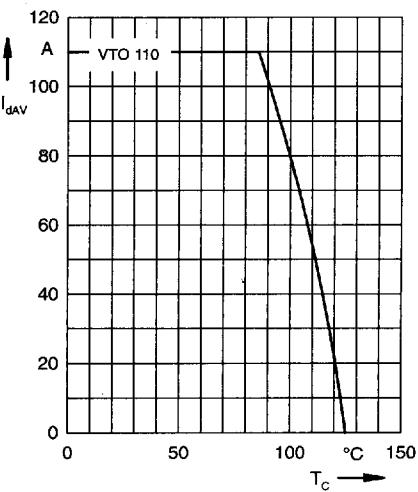
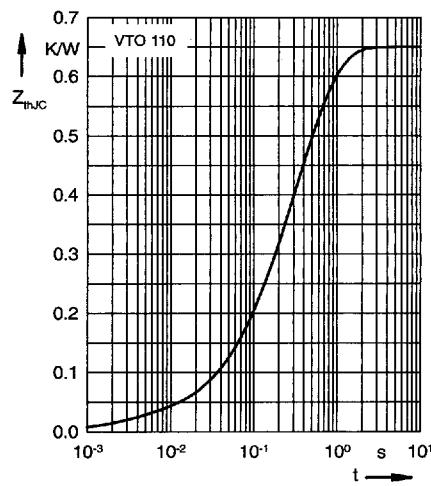


Fig. 2 DC output current at case temperature

Fig. 4 Transient thermal impedance junction to case (per leg)  
 $Z_{ThJC}$ : Transient thermal impedance,  $t$ : duration